



A Product Line of Diodes Incorporated



#### **100V PNP LOW SATURATION TRANSISTOR IN SOT23**

#### Features

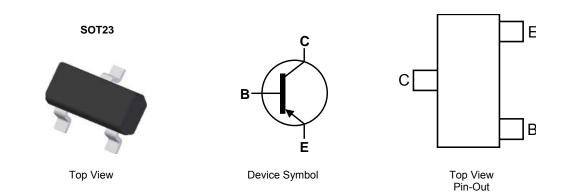
- BV<sub>CEO</sub> > -100V
- I<sub>C</sub> = -1A High Continuous Collector Current
- I<sub>CM</sub>= -2.5A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -330mV @ -1A</li>
- $R_{CE(SAT)} = 210m\Omega$  for a Low Equivalent On-Resistance
- 625mW Power Dissipation
- h<sub>FE</sub> Characterized up to -1.5A for High Current Gain Hold-Up
- Complementary NPN Type: FMMT624
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight 0.008 grams (Approximate)

#### Applications

- High-Side Driver
- Load Disconnect Switch
- Motor Drive



#### Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT723TA	AEC-Q101	723	7	8	3,000
FMMT723QTA	Automotive	723	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

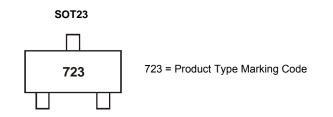
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**

Notes:







# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-100	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	I <sub>C</sub>	-1	A
Peak Pulse Current	I <sub>CM</sub>	-2.5	A
Base Current	Ι <sub>Β</sub>	-500	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	625	mW
Power Dissipation (Note 7)	PD	806	mW
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0JA</sub>	200	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R <sub>0JA</sub>	155	°C/W
Thermal Resistance, Junction to Leads (Note 8)	R <sub>θJL</sub>	194	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

#### ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 6. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

7. Same as Note 6, except the device is measured at t ≤ 5 sec.

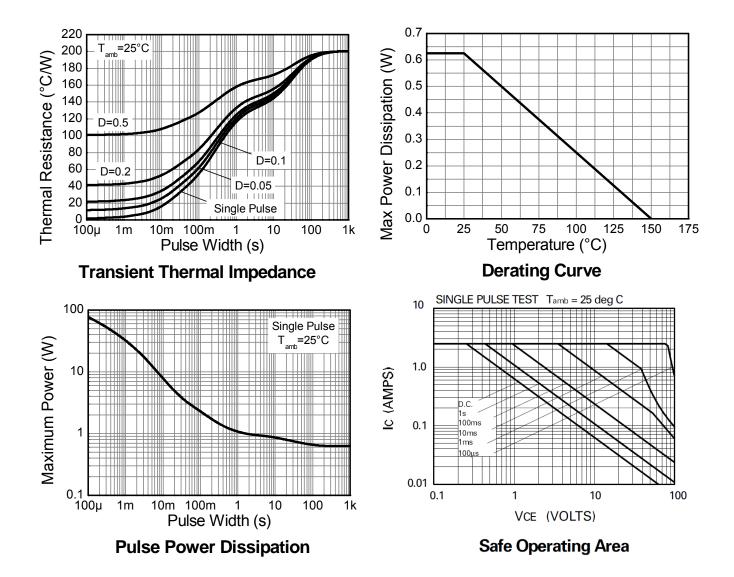
8. Thermal resistance from junction to solder-point (at the end of the collector lead).

9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





# Thermal Characteristics and Derating information







# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

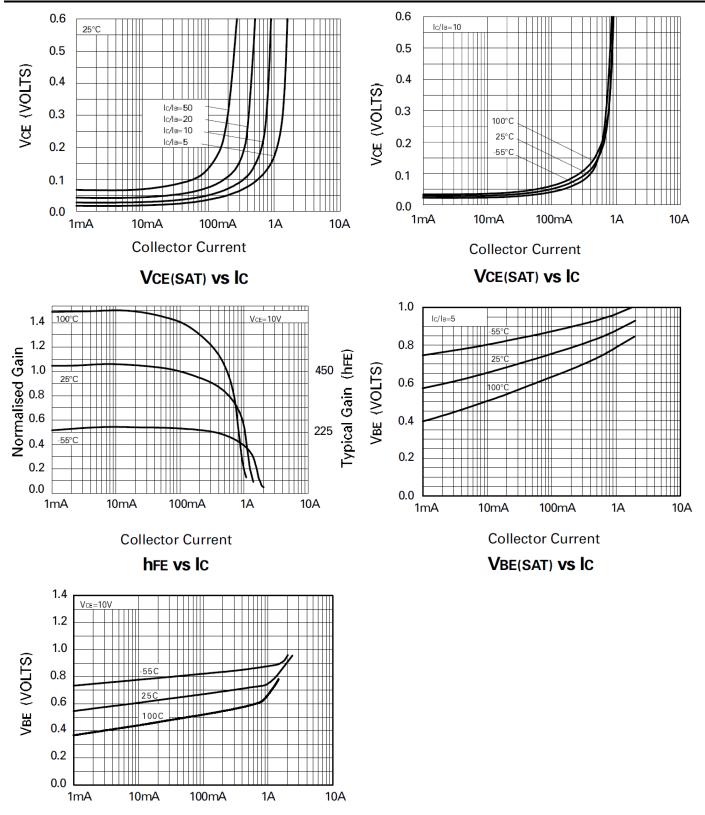
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-100	-200	-	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	-100	-160	-	V	$I_{\rm C}$ = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.8	-	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CBO</sub>	-	<1	-100	nA	V <sub>CB</sub> = -80V
Emitter Cutoff Current	I <sub>EBO</sub>	-	<1	-100	nA	V <sub>EB</sub> = -5.6V
Collector Emitter Cutoff Current	ICES	-	<1	-100	nA	V <sub>CE</sub> = -80V
		300	475	-	-	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -10V
		300	450	-		I <sub>C</sub> = -0.1A, V <sub>CE</sub> = -10V
Static Forward Current Transfer Ratio (Note 10)	h <sub>FE</sub>	250	375	-		I <sub>C</sub> = -0.5A, V <sub>CE</sub> = -10V
		-	250	-		I <sub>C</sub> = -1A, V <sub>CE</sub> = -10V
		-	30	-		I <sub>C</sub> = -1.5A, V <sub>CE</sub> = -10V
	V <sub>CE(sat)</sub>	-	-50	-80	mV	I <sub>C</sub> =- 0.1A, I <sub>B</sub> = -10mA
Collector-Emitter Saturation Voltage (Note 10)		-	-125	-200		I <sub>C</sub> = -0.5A, I <sub>B</sub> = -50mA
		-	-210	-330		I <sub>C</sub> = -1A, I <sub>B</sub> = -150mA
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(on)</sub>	-	-0.71	-1.0	V	I <sub>C</sub> = -1A, V <sub>CE</sub> = -10V
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(sat)</sub>	-	-0.89	-1.0	V	I <sub>C</sub> = -1A, I <sub>B</sub> = -150mA
Output Capacitance	C <sub>obo</sub>	-	13	20	pF	V <sub>CB</sub> = -10V, f = 1MHz
Transition Frequency	fT	150	200	-	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA, f = 100MHz
Turn-On Time	t <sub>on</sub>	-	50	-	ns	$V_{CC} = -50V, I_{C} = -0.5A$
Turn-Off Time	t <sub>off</sub>	-	760	-	ns	I <sub>B1</sub> = I <sub>B2</sub> = -50mA

Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.





# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



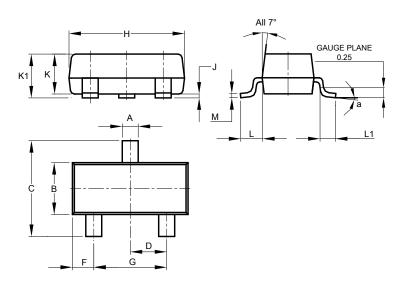
Collector Current **VBE(ON) vs IC** 





### **Package Outline Dimensions**

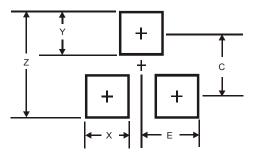
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT23					
Dim	MIN	Min Max Typ			
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
<b>ر</b>	0.013	0.10	0.05		
К	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	8°				
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

SOT23





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